TOSHIBA Photocoupler IRED & Photo-Transistor

TLP371, TLP372

Programmable Controllers Telecommunication Solid State Relay

The TOSHIBA TLP371 and TLP372 consists of an infrared emitting diode optically coupled to a Darlington connected photo-transistor which has an integrated base-emitter resistor to optimize switching speed and elevated temperature characteristics in a six lead plastic DIP package.

TLP372 has no-base internal connection for high-EMI environments.

Current transfer ratio : 1000% (min)

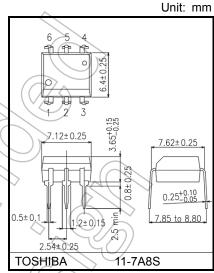
• Isolation voltage : 5000 Vrms (min)

UL-recognized : UL 1577, File No.E67349

cUL-recognized(TLP371): CSA Component Acceptance Service No.5A

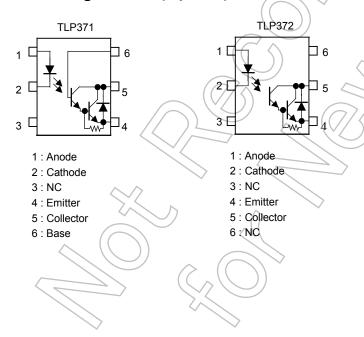
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CQC-approved(TLP371): GB4943.1,GB8898 Japan Factory



Weight: 0.4 g (typ.)

Pin Configurations (top view)



Start of commercial production 1986-03



Absolute Maximum Ratings (Ta = 25°C)

	Characteristics	Symbol	Rating	Unit
	Forward current	IF	60	mA
	Forward current derating (Ta ≥ 39°C)	ΔI _F /°C	-0.7	mA/°C
	Peak forward current (100 µs pulse, 100 pps)	IFP	1	Α
ΓED	Reverse voltage	V _R	5	V
	Diode power dissipation	PD	70) mW
	Diode power dissipation derating (Ta ≥39 °C)	ΔP _D /°C	-0.81	mW/°C
	Junction temperature	Tj	125	°C
	Collector-emitter voltage	V _{CEO}	300	V
	Collector-base voltage (TLP371)	V _{CBO}	300	V
	Emitter-collector voltage	VECO	0.3	V
ctor	Emitter-base voltage (TLP371)	V _{EBO}	7	/(v
Detector	Collector current	Ic (7/4	150	mA
	Power dissipation	PC	300	mW
	Power dissipation derating (Ta ≥ 25°C)	ΔP _C /°C	-3.0	mW/°C
	Junction temperature	\(\frac{1}{i}\)	125	°C
Stor	rage temperature range	T _{stg}	-55 to 125	°C
Оре	erating temperature range	Topr	-55 to 100	°C
Lea	d soldering temperature (10 s)	T _{sol}	260	°C
Tota	al package power dissipation	РТ	350	mW
Tota	al package power dissipation derating (Ta ≥ 25°C)	ΔΡτ/°C	-3.5	mW/°C
Isola	ation voltage (AC, 60 s, R.H. ≤ 60 %) (Note 1)	BVs	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 1: Device considered a two terminal device: Pins 1, 2 and 3 shorted together and pins 4,5 and 6 shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	Vcc	_	_	200	V
Forward current	lF	_	16	25	mA
Collector current	Ic	_	_	120	mA
Operating temperature	Topr	-25	1	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.



Electrical Characteristics (Ta = 25°C)

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I _F = 10 mA	1.0	1.15	1.3	V
E	Reverse current	IR	V _R = 5 V	_	_	10	μA
	Capacitance	Ст	V = 0 V, f = 1 MHz	١	30	1	pF
	Collector-emitter breakdown voltage	V _(BR) CEO	IC = 0.1 mA	300	_	1	V
	Emitter-collector breakdown voltage	V _{(BR)ECO}	I _E = 0.1 mA	0.3	-	-	V
Detector	Collector-base breakdown voltage (TLP371)	V _{(BR)CBO}	I _C = 0.1 mA	300	-	-	V
	Emitter-base breakdown voltage (TLP371)	V(BR)EBO	IE = 0.1 mA	7	-	1	V
	Collector dark current	ICEO	V _{CE} = 200 V	_	10	200	nA
			V _{CE} = 200 V, Ta = 85 °C	_	-	20	μΑ
	Collector dark current (TLP371)	ICER	V _{CE} = 200 V, Ta = 85 °C R _{BE} = 10 MΩ	-<	0.5	10	μΑ
	Collector dark current (TLP371)	I _{CBO}	V _{CB} = 200 V		0.1	-	nA
	DC forward current gain (TLP371)	hFE	V _{CE} = 5 V, I _C = 10 mA	(\bigcirc)	7000	_	_
	Capacitance (collector to emitter)	CCE	V = 0 V, f = 1 MHz	17	/10	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Mln	Тур.	Max	Unit
Current transfer ratio	Ic/IF	IF = 1 mA, VCE = 1 V	1000	4000	_	%
Saturated CTR	IC/IF(sat)	IF = 10 mA, VCE = 1 V	500	_	_	%
Base photo-current (TLP371)	IPB)	IF = 1 mA, V _{CB} = 1 V	_	6	-	μΑ
Collector-emitter saturation voltage		IC = 10 mA, IF = 1 mA	_	_	1.0	V
	VCE (sat)	I _C = 100 mA, I _F = 10 mA	0.3	_	1.2	V



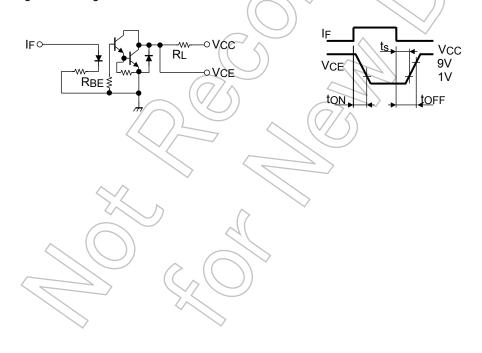
Isolation Characteristics (Ta = 25°C)

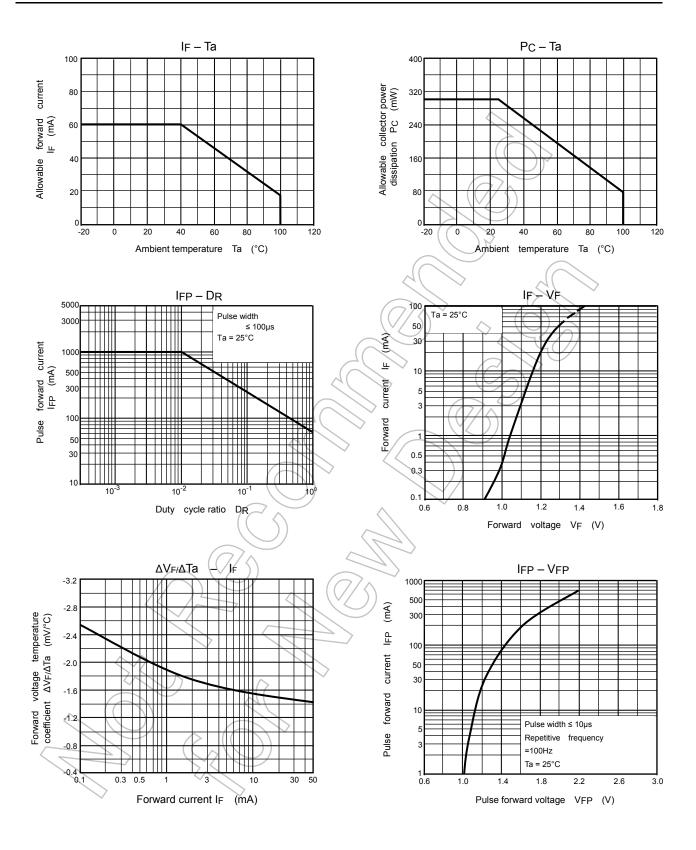
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input to output)	Cs	V _S = 0 V, f = 1 MHz	-	0.8	_	pF
Isolation resistance	Rs	V _S = 500 V, R.H. ≤ 60 %	5×10 ¹⁰	10 ¹⁴	_	Ω
Isolation voltage	BVs	AC, 60 s	5000	_	_	Vrms

Switching Characteristics (Ta = 25°C)

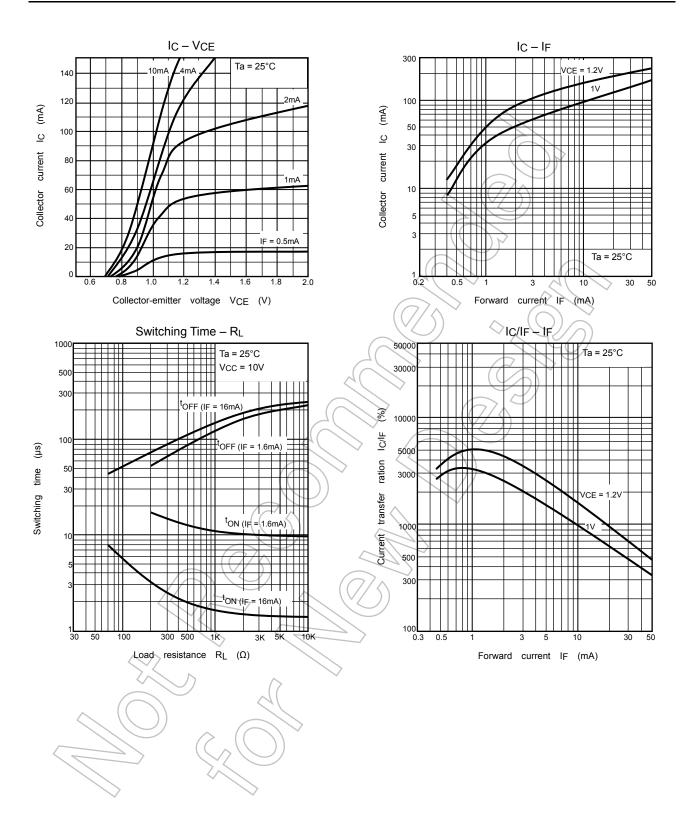
Characteristics	Symbol	Test Condition Min Typ. Max Un	nit
Rise time	tr	_ 40 _	
Fall time	tf	V _{CC} = 10 V I _C = 10 mA	•
Turn-on time	ton	I _C = 10 mA R _L = 100 Ω – 50	5
Turn-off time	t _{off}	— 15 —	
Turn-on time	ton	R _L = 180 Ω (Fig.1) 3 -	
Storage time	ts	R _{BE} = OPEN	S
Turn-off time	toff	V _{CC} = 10 V, I _F = 16 mA	
Turn-on time	ton	5 -	
Storage time	t _s	R_L = 180 Ω (Fig. 1) — 40 — με	s
Turn-off time	toff	VCC = 10 V, I _F = 16 mA	

Fig.1: Switching time test circuit

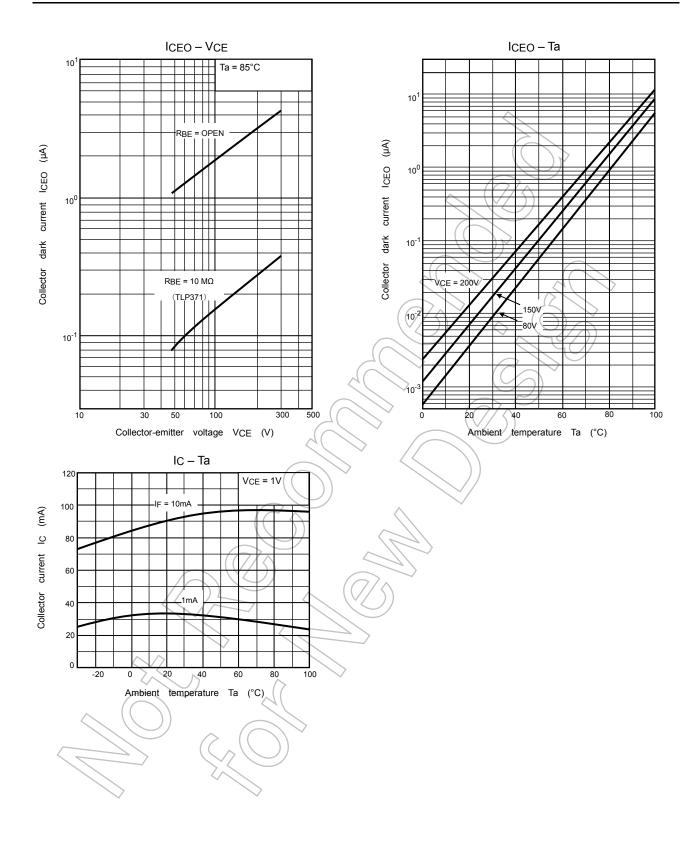




NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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